



14MHz, Rail-to-Rail I/O CMOS Operational Amplifier

1 FEATURES

- HIGH GAIN BANDWIDTH:14MHz
- RAIL-TO-RAIL INPUT AND OUTPUT ±0.6mV Typical Vos
- INPUT VOLTAGE RANGE: -0.1V to +5.6V with Vs = 5.5V
- SUPPLY RANGE: +2.5V to +5.5V
- SHUTDOWN: RS821S/RS822S
- SPECIFIED UP TO +125°C
- Micro SIZE PACKAGES: SOT23-5, SOT23-6

2 APPLICATIONS

- SENSORS
- PHOTODIODE AMPLIFICATION
- ACTIVE FILTERS
- TEST EQUIPMENT
- DRIVING A/D CONVERTERS

3 DESCRIPTIONS

The RS82X families of products offer low voltage operation and rail-to-rail input and output, as well as excellent speed/power consumption ratio, providing an excellent bandwidth (14MHz) and slew rate of 10V/us. The op-amps are unity gain stable and feature an ultra-low input bias current.

The devices are ideal for sensor interfaces, active filters and portable applications. The RS821S, RS822S include a shutdown mode. Under logic control, the amplifiers can be switched from normal operation to a standby current that is less than 1uA.The RS82X families of operational amplifiers are specified at the full temperature range of -40°C to +125°C under single or dual power supplies of 2.5V to 5.5V.

Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE(NOM)
	SOT23-5	2.90mm×1.60mm
RS821	SOT23-6	2.90mm×1.60mm
K3021	SOIC-8(SOP8)	4.90mm×3.90mm
	MSOP-8	3.00mm×3.00mm
	SOIC-8(SOP8)	4.90mm×3.90mm
	MSOP-8	3.00mm×3.00mm
RS822	TSSOP-8	3.00mm×4.40mm
	MSOP-10	3.00mm×3.00mm
	DFN2×2-8L	2.00mm×2.00mm
RS824	SOIC-14 (SOP14)	8.65mm×3.90mm
	TSSOP-14	5.00mm×4.40mm

⁽¹⁾ For all available packages, see the orderable addendum at the end of the data sheet.



Table of Contents

1 FEATURES	1
2 APPLICATIONS	1
3 DESCRIPTIONS	1
4 Revision History	3
5 PACKAGE/ORDERING INFORMATION (1)	4
6 Pin Configuration and Functions (Top View)	5
7 SPECIFICATIONS	8
7.1 Absolute Maximum Ratings	8
7.2 ESD Ratings	8
7.3 Recommended Operating Conditions	9
7.4 ELECTRICAL CHARACTERISTICS	10
7.5 TYPICAL CHARACTERISTICS	12
8 Detailed Description	15
8.1 Overview	15
8.2 RS821S/RS822S ENABLE FUNCTION	15
8.3 Phase Reversal Protection	15
8.4 EMI Rejection Ratio (EMIRR)	15
8.5 EMIRR IN+ Test Configuration	16
9 Application and Implementation	17
9.1 APPLICATION NOTE	17
9.2 25-kHz Low-pass Filter	17
9.3 Design Requirements	17
9.4 Detailed Design Procedure	17
9.5 Application Curve	18
10 Layout	19
10.1 Layout Guidelines	19
10.2 Layout Example	19
11 PACKAGE OUTLINE DIMENSIONS	20
12 TADE AND DEEL INCODMATION	20



4 Revision HistoryNote: Page numbers for previous revisions may different from page numbers in the current version.

Version	Change Date	Change Item
C.1	2022/05/25	 Update Package Qty on Page 2@RevB.4 Added TAPE AND REEL INFORMATION Added APPLICATION NOTE
C.2	2023/08/11	Added RS822XTDE8 Orderable Device



5 PACKAGE/ORDERING INFORMATION (1)

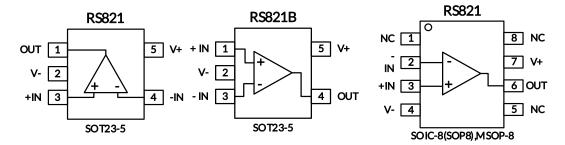
Orderable Device	Package Type	Pin	Channel	Op Temp(°C)	Device Marking ⁽²⁾	Package Qty
RS821XF	SOT23-5	5	1	-40°C ~125°C	821	Tape and Reel,3000
RS821BXF	SOT23-5	5	1	-40°C ~125°C	821B	Tape and Reel,3000
RS821XK	SOIC-8(SOP8)	8	1	-40°C ~125°C	RS821	Tape and Reel,4000
RS821XM	MSOP-8	8	1	-40°C ~125°C	RS821	Tape and Reel,4000
RS821SXK	SOIC-8(SOP8)	8	1	-40°C ~125°C	RS821S	Tape and Reel,4000
RS821SXH	SOT23-6	6	1	-40°C ~125°C	821S	Tape and Reel,3000
RS822XK	SOIC-8(SOP8)	8	2	-40°C ~125°C	RS822	Tape and Reel,4000
RS822XM	MSOP-8	8	2	-40°C ~125°C	RS822	Tape and Reel,4000
RS822XQ	TSSOP-8	8	2	-40°C ~125°C	RS822	Tape and Reel,4000
RS822SXN	MSOP-10	10	2	-40°C ~125°C	RS822S	Tape and Reel,4000
RS822XTDE8	DFN2x2-8L	8	2	-40°C ~125°C	822	Tape and Reel,3000
RS824XP	SOIC-14(SOP14)	14	4	-40°C ~125°C	RS824	Tape and Reel,4000
RS824XQ	TSSOP-14	14	4	-40°C ~125°C	RS824	Tape and Reel,4000

⁽¹⁾ This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.

⁽²⁾ There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.



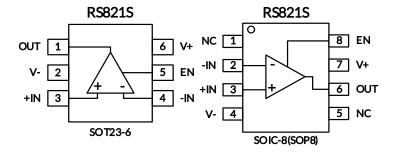
6 Pin Configuration and Functions (Top View)



Pin Description

PIN						
NAME	ME RS821 RS821B RS821		RS821	I/O (1)	DESCRIPTION	
	SOT23-5	SOT23-5	SOIC-8(SOP8)/MSOP-8			
-IN	4	3	2	I	Negative (inverting) input	
+IN	3	1	3	I	Positive (noninverting) input	
NC (2)	-	-	1,5,8	-	No internal connection (can be left floating)	
OUT	1	4	6	0	Output	
V-	2	2	4	-	Negative (lowest) power supply	
V+	5	5	7	-	Positive (highest) power supply	

- (1) I = Input, O = Output.
- (2) There is no internal connection. Typically, GND is the recommended connection to a heat spreading plane.



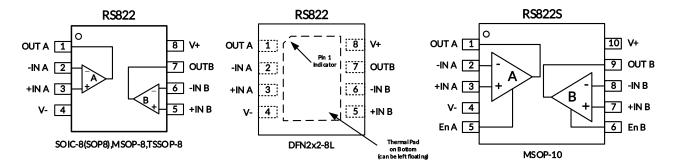
Pin Description

	NAME RS821S SOT23-6 SOIC-8(SOP8)					
NAME			I/O (1)	DESCRIPTION		
-IN	4	2	I	Inverting input		
+IN	3	3	I	Noninverting input		
OUT	1	6	0	Output		
EN	5	8	Ι	Enable pin. This pin turns the regulator on or off. Low = disabled, high = normal operation (pin must be driven)		
NC (2)		1,5	ı	No internal connection (can be left floating)		
V-	2 4		ı	Negative (lowest) power supply		
V+	6	7	-	Positive (highest) power supply		

- (1) I = Input, O = Output.
- (2) There is no internal connection. Typically, GND is the recommended connection to a heat spreading plane.



Pin Configuration and Functions (Top View)



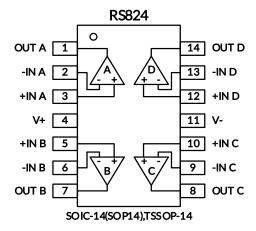
Pin Description

	PIN						
NANAE	RS822	RS822S	1/0(1)	DESCRIPTION			
NAME	SOIC-8(SOP8)/ MSOP-8/TSSOP-8 /DFN2×2-8L	MSOP-10	I/O ⁽¹⁾	DESCRIPTION			
-INA	2	2	I	Inverting input, channel A			
+INA	3	3	I	Noninverting input, channel A			
-INB	6	8	I	Inverting input, channel B			
+INB	5	7	I	Noninverting input, channel B			
OUTA	1	1	0	Output, channel A			
OUTB	7	9	0	Output, channel B			
EnA	-	5	I	Enable pin, channel A. This pin turns the regulator on or off. Low = disabled, high = normal operation (pin must be driven)			
EnB	-	6	I	Enable pin, channel B. This pin turns the regulator on or off. Low = disabled, high = normal operation (pin must be driven)			
V-	4	4	-	Negative (lowest) power supply			
V+	8	10	-	Positive (highest) power supply			
-	Thermal Pad	-	-	Connect thermal pad to V-			

⁽¹⁾ I = Input, O = Output.



Pin Configuration and Functions (Top View)



Pin Description

LIII DE2	iii Description						
NAME	PIN	I/O (1)	DESCRIPTION				
NAME	SOIC-14(SOP14)/TSSOP-14	1/0 \-/	DESCRIPTION				
-INA	2	I	Inverting input, channel A				
+INA	3	I	Noninverting input, channel A				
-INB	6	I	Inverting input, channel B				
+INB	5	- 1	Noninverting input, channel B				
-INC	9	- 1	Inverting input, channel C				
+INC	10	- 1	Noninverting input, channel C				
-IND	13	- 1	Inverting input, channel D				
+IND	12	- 1	Noninverting input, channel D				
OUTA	1	0	Output, channel A				
OUTB	7	0	Output, channel B				
OUTC	8	0	Output, channel C				
OUTD	14	0	Output, channel D				
V-	11	-	Negative (lowest) power supply				
V+	4	-	Positive (highest) power supply				

⁽¹⁾ I = Input, O = Output.



7 SPECIFICATIONS

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) (1)

			MIN	MAX	UNIT
	Supply, V _S =(V+) - (V-)			7	
Voltage	Supply, V _S =(V+) - (V-) Signal input pin ⁽²⁾ Signal output pin ⁽³⁾ Signal output pin ⁽³⁾ Output short-circuit ⁽⁴⁾ Package thermal impedance ⁽⁵⁾ Operating range, T _A Junction, T _J ⁽⁶⁾ Storage, T _{stg}		(V-)-0.5	(V+) +0.5	V
	Signal output pin (3)		(V-)-0.5	(V+) +0.5	
	Signal input pin ⁽²⁾		-10	10	mA
Current	Signal output pin (3)		-140	140	mA
	Output short-circuit (4)		Cont	7 (V+) +0.5 (V+) +0.5 10 140	
		SOT23-5		230	
		SOIC-8(SOP8)		110.88	
		MSOP-8		165.7	
		SOIC-14(SOP14)		104.5	
θ _{JA}	Package thermal impedance (5)	-10 10 m -140 140 m Continuous SOT23-5 SOIC-8(SOP8) 110.88 MSOP-8 165.7 SOIC-14(SOP14) 104.5 TSSOP-14 89.21 °C SOT23-6 230 TSSOP-8 240 DFN2×2-8L 80 MSOP-10 200 -40 125	°C/W		
			230	1	
		TSSOP-8		240	
		DFN2×2-8L		80	
		MSOP-10		200	
	Operating range, T _A	'	-40	125	
Temperature	Junction, T _J ⁽⁶⁾		-40	150	°C
	Storage, T _{stg}		-65	150	

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

- (2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less.
- (3) Output terminals are diode-clamped to the power-supply rails. Output signals that can swing more than 0.5V beyond the supply rails should be current-limited to ± 140 mA or less.
- (4) Short-circuit to ground, one amplifier per package.
- (5) The package thermal impedance is calculated in accordance with JESD-51.
- (6) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.

7.2 ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

		-	VALU	JE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001	±500	00	V
V (ESD)	Electrostatic discharge	Machine Model (MM)	±400	0	·

(1) JEDEC document JEP155 states that 500 V HBM allows safe manufacturing with a standard ESD control process.



ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



7.3 Recommended Operating ConditionsOver operating free-air temperature range (unless otherwise noted)

		MIN	МОМ	MAX	UNIT
Supply voltage , V _S = (V+) - (V-)	Single-supply	2.5		5.5	
Supply voltage , vs= (v+) - (v-)	Dual-supply	±1.25		±2.75	V



7.4 ELECTRICAL CHARACTERISTICS

(At T_A = +25°C, V_S =5V, R_L = 10k Ω connected to $V_S/2$, and V_{OUT} = $V_S/2$, V_{CM} = $V_S/2$, Full $^{(9)}$ = -40°C to +125°C, unless otherwise noted.) $^{(1)}$

noted.) ⁽¹⁾	PARAMETER	CONDITIONS	Tı			S, RS822S S822, RS82	4
	I ANAIVIETEN	CONDITIONS	.,	MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT
POWER	R SUPPLY						
Vs	Operating Voltage Range		25°C	2.5		5.5	V
IQ	Quiescent Current/Amplifier		25°C		1.9	2.5	mA
DCDD	B 6 1 B : 1: B ::	V _S =2.5V to 5.5V	25°C	75	88		10
PSRR	Power-Supply Rejection Ratio	V _{CM} = (V-)+0.5V	Full	65			dB
INPUT							
Vos	Input Offset Voltage	V _{CM} = V _S /2	25°C	-2.5	±0.6	2.5	mV
Vos Tc	Input Offset Voltage Average Drift	V _{CM} = V _S /2	Full		±1.6		uV/°C
IB	Input Bias Current (4) (5)		25°C		±1	±10	pА
los	Input Offset Current (4)		25°C		±1	±10	pА
V_{CM}	Common-Mode Voltage Range	V _S = 5.5V	25°C	-0.1		5.6	V
		V _S = 5.5V,	25°C	75	88		
CMRR	Common Mada Paiastian Patia	V _{CM} =-0.1V to 4V	Full	67			dB
CIVIKK	Common-Mode Rejection Ratio	V _S = 5.5V,	25°C	61	75		
		V _{CM} =-0.1V to 5.6V	Full	58			
OUTPU	т						
		$R_L=2K\Omega$,	25°C	91	100		
۸	A _{OL} Open-Loop Voltage Gain	Vo=0.15V to 4.85V	Full	78			dB
AOL		R _L =10KΩ, Vo= 0.05V to 4.95V	25°C	89	98		_ ub
			Full	75			
	Output Swing From Rail	R _L =2KΩ	25°C		20		mV
	Output Swillig From Kali	R _L =10KΩ			7		
lout	Output Short-Circuit Current (6) (7)		25°C		±110		mA
FREQU	ENCY RESPONSE						
SR	Slew Rate (8)		25°C		10		V/us
GBP	Gain-Bandwidth Product		25°C		14		MHz
PM	Phase Margin		25°C		58		0
ts	Setting Time,0.1%				0.2		us
	Overload Recovery Time	V _{IN} •Gain≥V _S			0.3		us
NOISE							
_	Input Voltage Noise Density	f = 1KHz	25°C		8.5		nV/√Hz
en	input voltage Noise Delisity	f = 10KHz	25°C		5.5		nV/√Hz
ENABLI	E/SHUTDOWN (RS821S, RS822S)	,					
I _{Q(OFF)}	Supply Current in Shutdown		25°C		<1		uA
toff			25°C		3		us
ton			25°C		20		us
V_{L}	Shut Down		25°C	V-		(V-)+0.8	V
V_{H}	Amplifier Is Active		25°C	(V-)+2		V+	V



- (1) Electrical table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device.
- (2) Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.
- (4) This parameter is ensured by design and/or characterization and is not tested in production.
- (5) Positive current corresponds to current flowing into the device.
- (6) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is PD = $(T_{J(MAX)} T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.
- (7) Short circuit test is a momentary test.
- (8) Number specified is the slower of positive and negative slew rates.
- (9) Specified by characterization only.

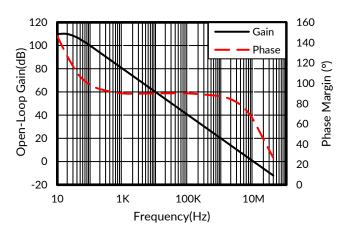


7.5 TYPICAL CHARACTERISTICS

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

120

At T_A = +25°C, V_S =5V, R_L = 10k Ω connected to $V_S/2$, V_{OUT} = $V_S/2$, unless otherwise noted.

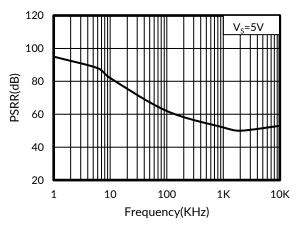


100 80 40 40 100 100 1K 10K Frequency(KHz)

Figure 1. Open-Loop Gain and Phase vs Frequency

100 100 1K 10K 100K

Figure 2. Common-Mode Rejection Ratio vs Frequency



Frequency(Hz)

Figure 3. Input Voltage Noise Spectral Density vs

Frequency

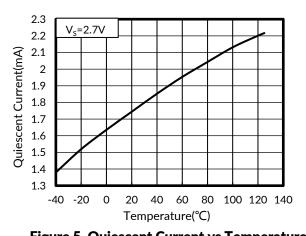


Figure 4. Power-Supply Rejection Ratio vs Frequency

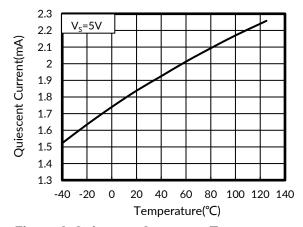


Figure 5. Quiescent Current vs Temperature

Figure 6. Quiescent Current vs Temperature

12 / 30 www.run-ic.com



TYPICAL CHARACTERISTICS

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, V_S =5V, R_L = 10k Ω connected to $V_S/2$, V_{OUT} = $V_S/2$, unless otherwise noted.

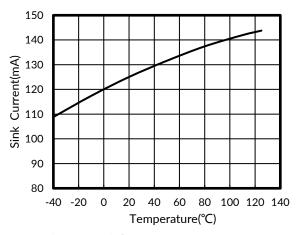


Figure 7. Sink Current vs Temperature

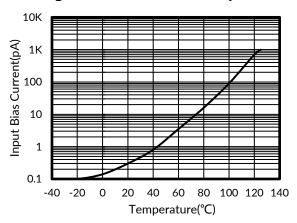


Figure 9. Input Bias Current vs Temperature

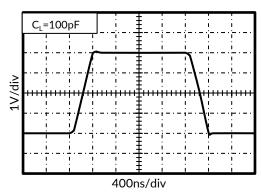


Figure 11. Large-Signal Step Response

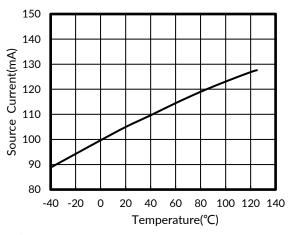


Figure 8. Source Current vs Temperature

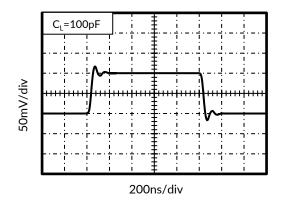


Figure 10. Small-Signal Step Response

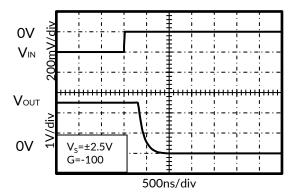


Figure 12. Positive Overvoltage Recovery



TYPICAL CHARACTERISTICS

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, V_S =5V, R_L = 10k Ω connected to $V_S/2$, V_{OUT} = $V_S/2$, unless otherwise noted.

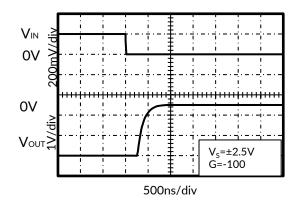


Figure 13. Negative Overvoltage Recovery

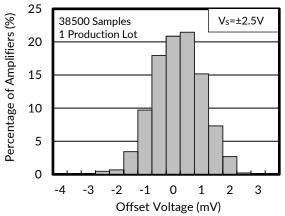


Figure 14. Offset Voltage Production Distribution



8 Detailed Description

8.1 Overview

The RS821, RS824, RS8215, RS822S are high precision, rail-to-rail operational amplifiers that can be run from a single-supply voltage 2.5V to 5.5V (±1.25V to ±2.75V). Supply voltages higher than 7V (absolute maximum) can permanently damage the amplifier. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications. Good layout practice mandates use of a 0.1uF capacitor place closely across the supply pins.

8.2 RS821S/RS822S ENABLE FUNCTION

The RS821S/RS822S includes a shutdown mode. Under logic control, the amplifiers can be switched from normal mode to a standby current of 1uA. When the Enable pin is connected to high, the amplifier is active. Connecting Enable low disables the amplifier, and places the amplifier, and place the output in a high-impedance state.

8.3 Phase Reversal Protection

The RS82X family has internal phase-reversal protection. Many op amps exhibit phase reversal when the input is driven beyond the linear common-mode range. This condition is most often encountered in noninverting circuits when the input is driven beyond the specified common-mode voltage range, causing the output to reverse into the opposite rail. The input of the RS82X prevents phase reversal with excessive common-mode voltage. Instead, the appropriate rail limits the output voltage. This performance is shown in figure 15.

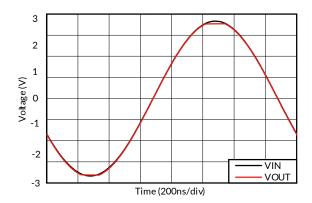


Figure 15. Output Waveform Devoid of Phase Reversal During an Input Overdrive Condition

8.4 EMI Rejection Ratio (EMIRR)

The electromagnetic interference (EMI) rejection ratio, or EMIRR, describes the EMI immunity of operational amplifiers. An adverse effect that is common to many operational amplifiers is a change in the offset voltage as a result of RF signal rectification. An operational amplifier that is more efficient at rejecting this change in offset as a result of EMI has a higher EMIRR and is quantified by a decibel value. Measuring EMIRR can be performed in many ways, but this document provides the EMIRR IN+, which specifically describes the EMIRR performance when the RF signal is applied to the noninverting input pin of the operational amplifier. In general, only the noninverting input is tested for EMIRR for the following three reasons:

- Operational amplifier input pins are known to be the most sensitive to EMI, and typically rectify RF signals better than the supply or output pins.
- The noninverting and inverting operational amplifier inputs have symmetrical physical layouts and exhibit nearly matching EMIRR performance.
- EMIRR is easier to measure on noninverting pins than on other pins because the noninverting input pin can be isolated on a printed-circuit-board (PCB). This isolation allows the RF signal to be applied directly to the noninverting input pin with no complex interactions from other components or connecting PCB traces.



Detailed Description (continued)

The EMIRR IN+ of the RS82X is plotted versus frequency in Figure 16. If available, any dual and quad operational amplifier device versions have approximately identical EMIRR IN+ performance. The RS82X unity-gain bandwidth is 14MHz. EMIRR performance below this frequency denotes interfering signals that fall within the operational amplifier bandwidth.

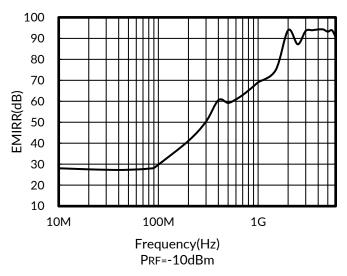


Figure 16. RS82X EMIRR vs Frequency

8.5 EMIRR IN+ Test Configuration

Figure 17 shows the circuit configuration for testing the EMIRR IN+. An RF source is connected to the operational amplifier noninverting input pin using a transmission line. The operational amplifier is configured in a unity-gain buffer topology with the output connected to a low-pass filter (LPF) and a digital multimeter (DMM). A large impedance mismatch at the operational amplifier input causes a voltage reflection; however, this effect is characterized and accounted for when determining the EMIRR IN+. The resulting dc offset voltage is sampled and measured by the multimeter. The LPF isolates the multimeter from residual RF signals that can interfere with multimeter accuracy.

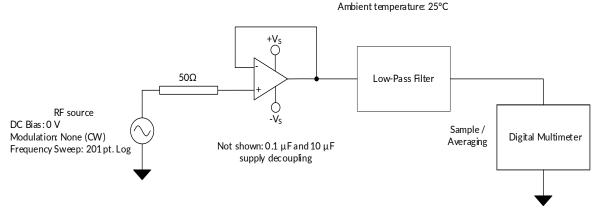


Figure 17. EMIRR IN+ Test Configuration Schematic



9 Application and Implementation

Information in the following applications sections is not part of the RUNIC component specification, and RUNIC does not warrant its accuracy or completeness. RUNIC's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 APPLICATION NOTE

The RS82X are high precision, rail-to-rail operational amplifiers that can be run from a single-supply voltage 2.5V to 5.5V ($\pm 1.25V$ to $\pm 2.75V$). Supply voltages higher than 7V (absolute maximum) can permanently damage the amplifier. Rail-to-rail input and output swing significantly increases dynamic range, especially in low-supply applications. Good layout practice mandates use of a 0.1uF capacitor place closely across the supply pins.

Typical Applications 9.2 25-kHz Low-pass Filter

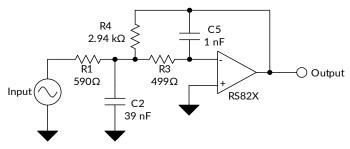


Figure 18. 25-kHz Low-Pass Filter

9.3 Design Requirements

Low-pass filters are commonly employed in signal processing applications to reduce noise and prevent aliasing. The RS82X devices are ideally suited to construct high-speed, high-precision active filters. Figure 18 shows a second-order, low-pass filter commonly encountered in signal processing applications.

Use the following parameters for this design example:

- Gain = 5 V/V (inverting gain)
- Low-pass cutoff frequency = 25 kHz
- Second-order Chebyshev filter response with 3-dB gain peaking in the passband

9.4 Detailed Design Procedure

The infinite-gain multiple-feedback circuit for a low-pass network function is shown in Figure 18. Use Equation 1 to calculate the voltage transfer function.

$$\frac{\text{Output}}{\text{Input}}(s) = \frac{-1/R_1R_3C_2C_5}{s^2 + (s/C_2)(1/R_1 + 1/R_3 + 1/R_4) + 1/R_3R_4C_2C_5}$$
(1)

This circuit produces a signal inversion. For this circuit, the gain at dc and the low-pass cutoff frequency are calculated by Equation 2:

Gain =
$$\frac{R_4}{R_1}$$

 $f_C = \frac{1}{2\pi} \sqrt{(1/R_3 R_4 C_2 C_5)}$

(2)



9.5 Application Curve

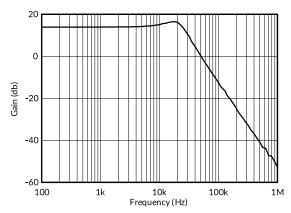


Figure 19. Low-pass filter transfer function



10 Layout

10.1 Layout Guidelines

Attention to good layout practices is always recommended. Keep traces short. When possible, use a PCB ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1uF capacitor closely across the supply pins.

These guidelines should be applied throughout the analog circuit to improve performance and provide benefits such as reducing the EMI susceptibility.

10.2 Layout Example

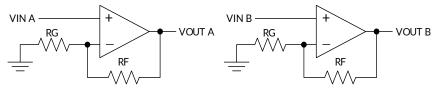


Figure 20. Schematic Representation

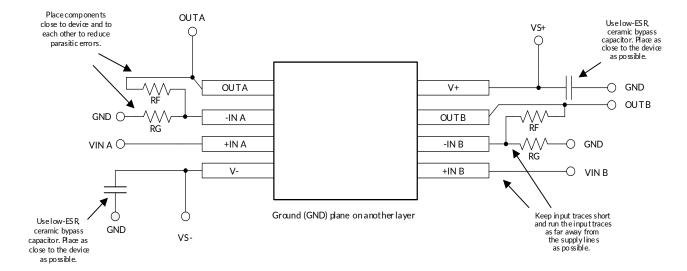
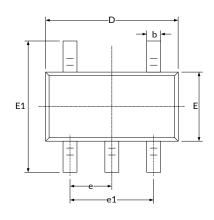


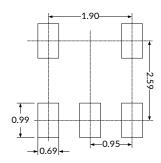
Figure 21. Layout Example

NOTE: Layout Recommendations have been shown for dual op-amp only, follow similar precautions for Single and four.

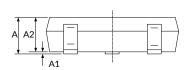


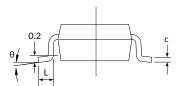
11 PACKAGE OUTLINE DIMENSIONS SOT23-5 (3)





RECOMMENDED LAND PATTERN (Unit: mm)



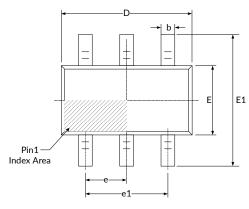


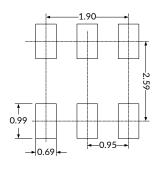
Complete	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Max	Min	Max	
A ⁽¹⁾	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D ⁽¹⁾	2.820	3.020	0.111	0.119	
E ⁽¹⁾	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950(BSC) (2)	0.037(BSC) (2)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	θ 0° 8°		0°	8°	

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.

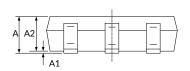


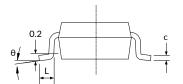
SOT23-6(3)





RECOMMENDED LAND PATTERN (Unit: mm)



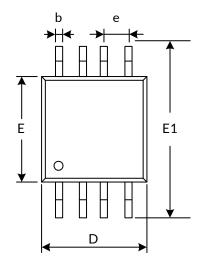


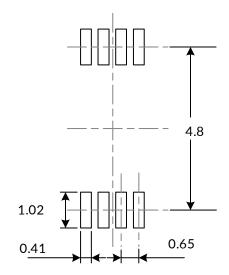
Complete	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Min Max		Max	
A ⁽¹⁾	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500 0.012		0.020	
С	0.100	0.200	0.004	0.008	
D (1)	2.820	3.020	0.111	0.119	
E ⁽¹⁾	E ⁽¹⁾ 1.500 1.700		0.059	0.067	
E1	2.650	2.950	0.104	0.116	
е	0.950(BSC) (2)	0.037(BSC) (2)	
e1	1.800	2.000	0.071	0.079	
L	0.300	0.600	0.012	0.024	
θ	θ 0° 8°		0°	8°	

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
 This drawing is subject to change without notice.

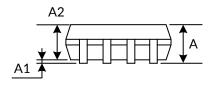


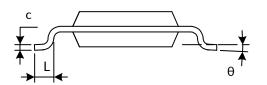
MSOP-8 (3)





RECOMMENDED LAND PATTERN (Unit: mm)



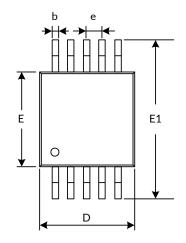


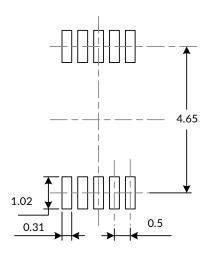
Complete	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Min Max		Max	
A (1)	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.250	0.380	0.010	0.015	
С	0.090	0.230	0.004	0.009	
D (1)	2.900	2.900 3.100		0.122	
е	0.650(BSC) (2)	0.026(BSC) ⁽²⁾	
E ⁽¹⁾	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
L	0.400	0.800	0.016	0.031	
θ	θ 0° 6°		0°	6°	

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- Plastic Brinding of State and No. 128 min maximum per state are not
 BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
 This drawing is subject to change without notice.

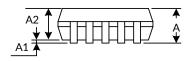


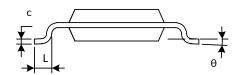
MSOP-10⁽³⁾





RECOMMENDED LAND PATTERN (Unit: mm)



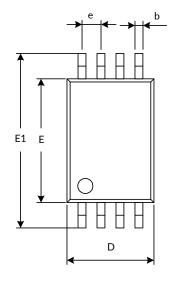


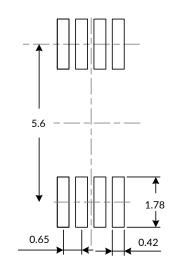
Cymah al	Dimensions I	n Millimeters	Dimensions In Inches			
Symbol	Min Max		Min	Max		
A (1)	0.820	1.100	0.032	0.043		
A1	0.020	0.150	0.001	0.006		
A2	0.750	0.950	0.030	0.037		
b	0.180 0.280		0.007	0.011		
С	0.090	0.230	0.004	0.009		
D (1)	2.900	3.100	0.114	0.122		
e	0.50(E	BSC) ⁽²⁾	0.020(BSC) ⁽²⁾		
E (1)	2.900	3.100	0.114	0.122		
E1	4.750 5.050		4.750 5.050 0.187		0.187	0.199
L	L 0.400 0.800		0.016	0.031		
θ	θ 0° 6°		0°	6°		

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
 This drawing is subject to change without notice.



TSSOP-8(3)





RECOMMENDED LAND PATTERN (Unit: mm)



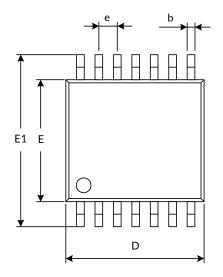


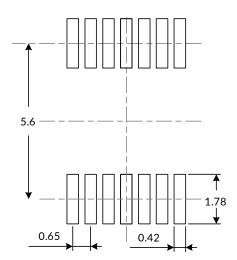
Complete	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Мах	Min	Max	
A ⁽¹⁾		1.200		0.047	
A1	0.050	0.150	0.002	0.006	
A2	0.800	1.050	0.031	0.041	
b	0.190 0.300		0.007	0.012	
С	0.090	0.200	0.004	0.008	
D ⁽¹⁾	2.900	3.100	0.114	0.122	
E ⁽¹⁾	4.300 4.500		0.169	0.177	
E1	6.250	6.550	0.246	0.258	
e	0.650(BSC) (2)		0.026(BSC) ⁽²⁾	
L	0.500	0.700	0.020	0.028	
Н	0.25(TYP)		0.01	(TYP)	
θ	1°	7°	1°	7°	

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.



TSSOP-14 (3)





RECOMMENDED LAND PATTERN (Unit: mm)



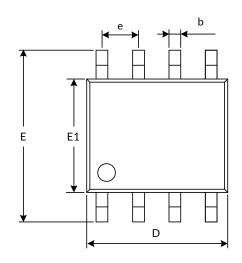


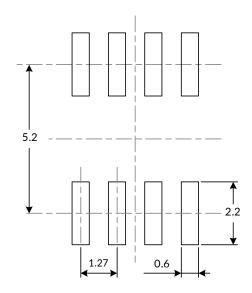
Comple of	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Max	Min	Max	
A (1)		1.200		0.047	
A1	0.050	0.150	0.002	0.006	
A2	0.800	1.050	0.031	0.041	
b	0.190	0.300 0.007		0.012	
С	0.090	0.200	0.004	0.008	
D (1)	4.860	5.100	0.191	0.201	
E (1)	4.300 4.500		0.169	0.177	
E1	6.250 6.550		0.246	0.258	
е	0.650(BSC) (2)	0.026(BSC) ⁽²⁾	
L	0.500	0.700	0.020	0.028	
Н	0.25(TYP)		0.01	(TYP)	
θ	1°	7°	1°	7°	

- Plastic or metal protrusions of 0.15mm maximum per side are not included.
 BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.

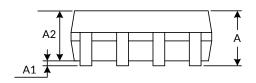


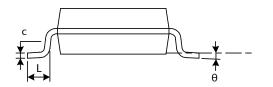
SOIC-8(SOP8) (3)





RECOMMENDED LAND PATTERN (Unit: mm)



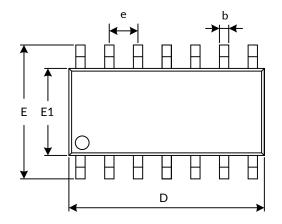


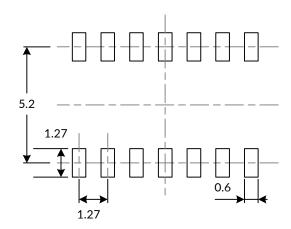
Complete	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Мах	Min	Max	
A (1)	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.007	0.010	
D ⁽¹⁾	4.800	5.000	0.189	0.197	
e	1.270(BSC) (2)	0.050(BSC) ⁽²⁾	
Е	5.800	6.200	0.228	0.244	
E1 ⁽¹⁾	3.800	4.000	0.150	0.157	
L	0.400	1.270	0.016	0.050	
θ	0° 8°		0°	8°	

- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.

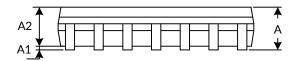


SOIC-14(SOP14)(3)





RECOMMENDED LAND PATTERN (Unit: mm)



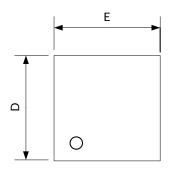


Combal	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Max	Min	Max	
A ⁽¹⁾	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	A2 1.350 1.550		0.053	0.061	
b	0.310	0.510	0.012	0.020	
С	0.100	0.250	0.004	0.010	
D (1)	8.450	8.850	0.333	0.348	
e	1.270(BSC) (2)	0.050(BSC) ⁽²⁾	
Е	5.800	6.200	0.228	0.244	
E1 ⁽¹⁾	3.800	4.000	0.150	0.157	
L	L 0.400 1.270		0.016	0.050	
θ	θ 0° 8°		0°	8°	

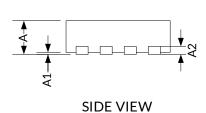
- 1. Plastic or metal protrusions of 0.15mm maximum per side are not included.
- 2. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 3. This drawing is subject to change without notice.

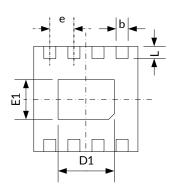


DFN-2x2-8L(4)

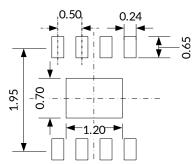


TOP VIEW





BOTTOM VIEW



RECOMMENDED LAND PATTERN

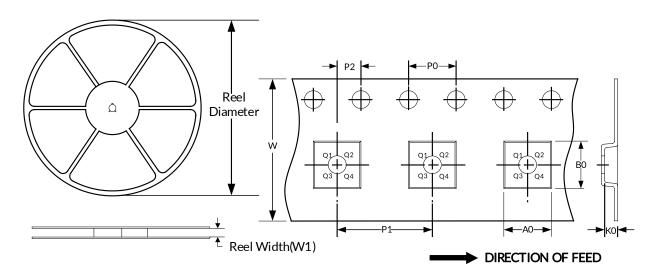
Symbol	Dimensions I	n Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
A ⁽¹⁾	0.700	0.800	0.028	0.031		
A1	0.000	0.050	0.000	0.002		
A2	0.203(REF) ⁽²⁾	0.008(REF) ⁽²⁾			
b	0.180	0.300	0.007	0.012		
D ⁽¹⁾	1.900	2.100	0.075	0.083		
D1	1.500	1.700	0.059	0.067		
E ⁽¹⁾	1.900	2.100	0.075	0.083		
E1	0.800	1.000	0.031	0.039		
е	0.500(BSC) ⁽³⁾		0.020(1	BSC) (3)		
L	L 0.250		0.250 0.350		0.010	0.014

- 1. Plastic or metal protrusions of 0.075mm maximum per side are not included.
- 2. REF is the abbreviation for Reference.3. BSC (Basic Spacing between Centers), "Basic" spacing is nominal.
- 4. This drawing is subject to change without notice.



12 TAPE AND REEL INFORMATION REEL DIMENSIONS

TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width(mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SOT23-6	7"	9.5	3.17	3.23	1.37	4.0	4.0	2.0	8.0	Q3
SOIC-8(SOP8)	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP-8	13"	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1
MSOP-10	13"	12.4	5.20	3.30	1.20	4.0	8.0	2.0	12.0	Q1
SOIC-14(SOP14)	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP-8	13"	12.4	6.90	3.45	1.65	4.0	8.0	2.0	12.0	Q1
TSSOP-14	13"	12.4	6.95	5.60	1.20	4.0	8.0	2.0	12.0	Q1
DFN2x2-8L	7"	9.5	2.30	2.30	1.10	4.0	4.0	2.0	8.0	Q2

- 1. All dimensions are nominal.
- 2. Plastic or metal protrusions of 0.15mm maximum per side are not included.



IMPORTANT NOTICE AND DISCLAIMER

Jiangsu RUNIC Technology Co., Ltd. will accurately and reliably provide technical and reliability data (including data sheets), design resources (including reference designs), application or other design advice, WEB tools, safety information and other resources, without warranty of any defect, and will not make any express or implied warranty, including but not limited to the warranty of merchantability Implied warranty that it is suitable for a specific purpose or does not infringe the intellectual property rights of any third party.

These resources are intended for skilled developers designing with RUNIC products You will be solely responsible for: (1) Selecting the appropriate products for your application; (2) Designing, validating and testing your application; (3) Ensuring your application meets applicable standards and any other safety, security or other requirements; (4) RUNIC and the RUNIC logo are registered trademarks of RUNIC INCORPORATED. All trademarks are the property of their respective owners; (5) For change details, review the revision history included in any revised document. The resources are subject to change without notice. Our company will not be liable for the use of this product and the infringement of patents or third-party intellectual property rights due to its use.